

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

FMR09N90E

D(2)

S(3)

TO-3PML package

2, Drain 3, Source

D

 Low input Low gate 100% av Minimum performation 	-3PML package ut capacitance and gate charge e input resistance valanche tested n Lot-to-Lot variations for robust devi ance and reliable operation	Image: constraint of the second se			
 Load sw 	ng applications /itch nanagement				
	UTE MAXIMUM RATINGS(Ta=25℃)				
SYMBOL	PARAMETER	VAL	UE	UNIT	
V _{DSS}	Drain-Source Voltage	90	0	V	
V _{GSS}	Gate-Source Voltage	±3	30	V	K [†]
ID	Drain Current-Continuous	9	,	A	↓
I _{DM}	Drain Current-Single Pulsed	36	6	А	-= R -= - N -
PD	Total Dissipation @Tc=25℃	10	0	W	mm DIM MIN MAX A 19.90 20.10
Tj	Max. Operating Junction Temperature	15	0	°C	B 15.75 16.10 C 5.50 5.70
T _{stg}	Storage Temperature	-55~	150	°C	D 0.90 1.10 F 3.30 3.50 G 2.90 3.20
• THERM	AL CHARACTERISTICS	H 5.90 6.10 J 0.595 0.70			
SYMBOL	PARAMETER		МАХ	UNIT	K 21.10 22.50 L 1.90 2.25 N 10.80 11.00
Rth(ch-c)	Channel-to-case thermal resistance		1.25	°C/W	Q 4.90 5.10 R 3.75 3.95
Rth(ch-a)	Channel-to-ambient thermal resistance		62.5	°C/W	S 3.20 3.60 U 9.90 10.10 Y 4.20 4.90 Z 1.90 2.10
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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	900			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =4.5A		1.16	1.4	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =900V; V _{GS} = 0V;Tc=25°C V _{DS} =720V; V _{GS} = 0V;Tc=25°C			25 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =9A, V _{GS} = 0 V			1.35	V

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2